

# March 2008 Ultrafast Rectifier

# FFA40UP35S

#### **Features**

- High Speed Switching,  $t_{rr} < 55$ ns @  $I_F = 40$ A
- · High Reverse Voltage and High Reliability
- · Avalanche Energy Rated
- Low Forward Voltage, V<sub>F</sub> < 1.6V
- · RoHS compliant

### **Applications**

- · General Purpose
- Switching Mode Power Supply
- Free-wheeling diode for motor application
- · Power switching circuits



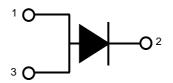
#### 40A, 350V Ultrafast Rectifier

The FFA40UP35S is utrafast rectifier with low forward voltage drop. It is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling/clamping rectifiers in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.



1. Anode 2. Cathode 3. Anode



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# Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{RRM}$	Peak Repetitive Reverse Voltage	350	V
$V_{RWM}$	Working Peak Reverse Voltage	350	V
$V_R$	DC Blocking Voltage	350	V
I <sub>F(AV)</sub>	Average Rectified Forward Current @ T <sub>C</sub> = 111°C	40	Α
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	400	А
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-65 to +150	°C

#### **Thermal Characteristics**

Symbol	Parameter	Ratings	Units
$R_{\thetaJC}$	Maximum Thermal Resistance, Junction to Case	0.8	°C/W

## **Package Marking and Ordering Information**

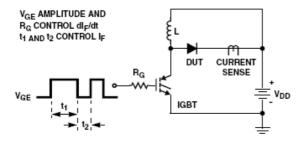
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F40UP35S	FFA40UP35STU	TO3P	-	-	30

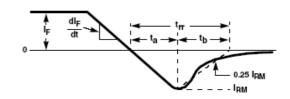
# **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Min.	Тур.	Max.	Units
V 4	I <sub>F</sub> = 40A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	-	1.6	V
V <sub>FM</sub> 1	I <sub>F</sub> = 40A	$T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$	-	-	1.5	V
115.41	$V_R = 350V$	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$	-	-	100	
	$V_R = 350V$	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	-	500	μА
t <sub>rr</sub>	$I_F = 1A$ , di/dt = 100A/ $\mu$ s, $V_R = 30V$		-	26	53	ns
	$I_F = 40A$ , di/dt = 200A/ $\mu$ s, $V_R = 230V$		-	28	55	
t <sub>a</sub>			-	17	-	ns
t <sub>b</sub>	$I_F = 40A$ , di/dt = 200A/ $\mu$ s, $V_R = 230V$	$T_C = 25^{\circ}C$	-	11	-	ns
$Q_{rr}$			-	36	-	nC
$W_{AVL}$	Avalanche Energy ( L = 40mH)		20	-	-	mJ

Notes: 1: Pulse: Test Pulse width =  $300\mu s$ , Duty Cycle = 2%

# **Test Circuit and Waveforms**

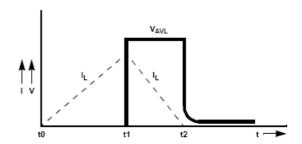




L = 40mH  $R \le 0.1\Omega$  $V_{DD} = 50V$ 

 $\mathsf{EAVL} = 1/2\mathsf{LI2} \; [\mathsf{V}_{\mathsf{R}(\mathsf{AVL})}/(\mathsf{V}_{\mathsf{R}(\mathsf{AVL})} \cdot \mathsf{V}_{\mathsf{DD}})]$ 

Q1 = IGBT (BV<sub>CES</sub> > DUT V<sub>R(AVL)</sub>) CURRENT  $V_{DD}$ SENSE  $V_{DD}$ 



# **Typical Performance Characteristics**

Figure 1. Typical Forward Voltage Drop vs. Forward Current

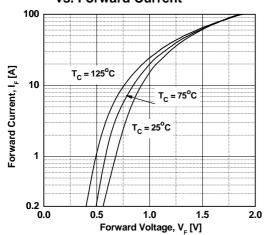


Figure 3. Typical Junction Capacitance

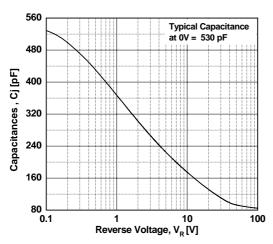


Figure 5. Typical Reverse Recovery Current vs. di/dt

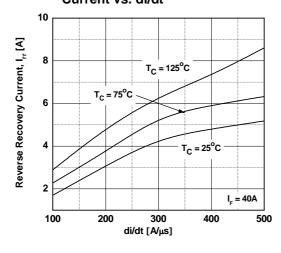


Figure 2. Typical Reverse Current vs. Reverse Voltage

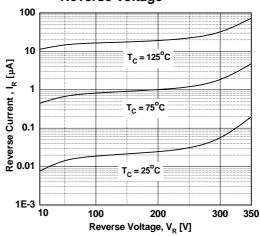
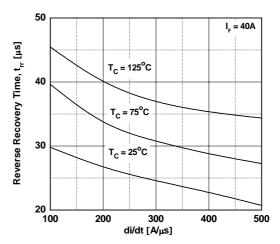
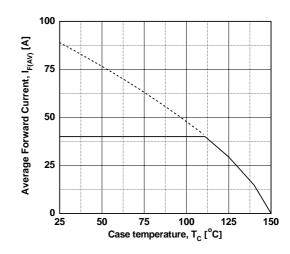


Figure 4. Typical Reverse Recovery Time vs. di/dt

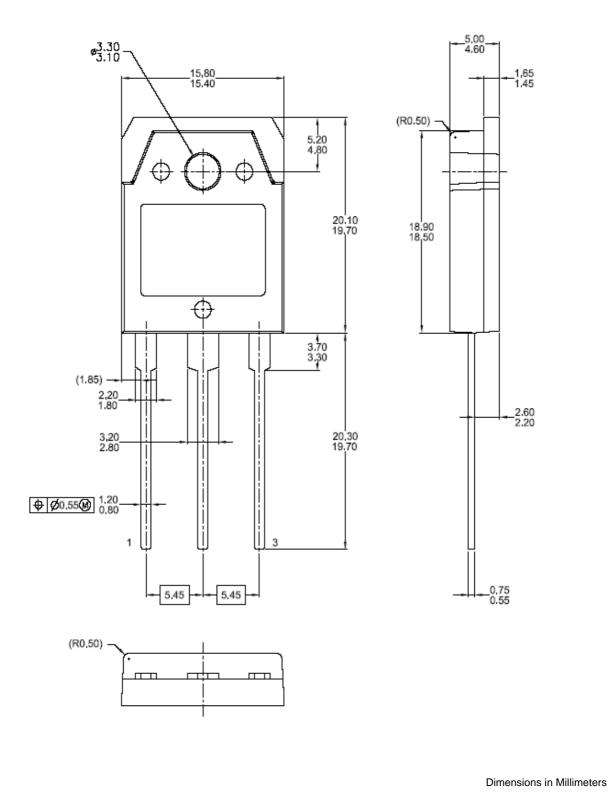


**Figure 6. Forward Current Derating Curve** 



# **Mechanical Dimensions**

# **TO3P**







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